

Supporting Information

Combining experiment and computation to elucidate the optical properties of Ce^{3+} in $\text{Ba}_5\text{Si}_8\text{O}_{21}$

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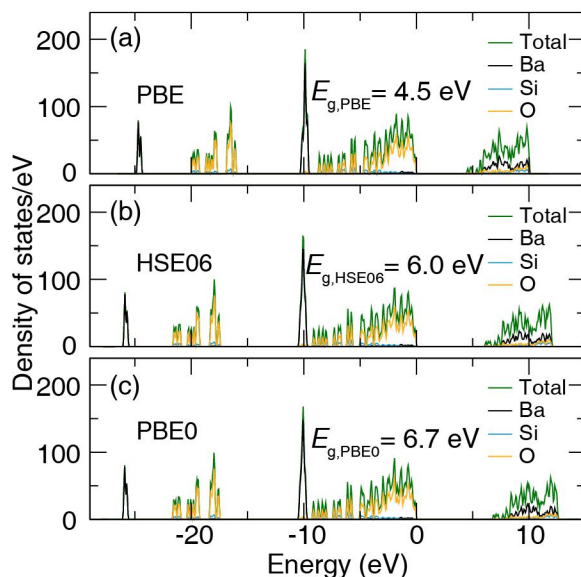


Figure S1 Density of states (DOS) of $\text{Ba}_5\text{Si}_8\text{O}_{21}$ and resulting band gap calculated with the a) PBE functional, b) HSE06 hybrid functional, and c) PBE0 hybrid functional.

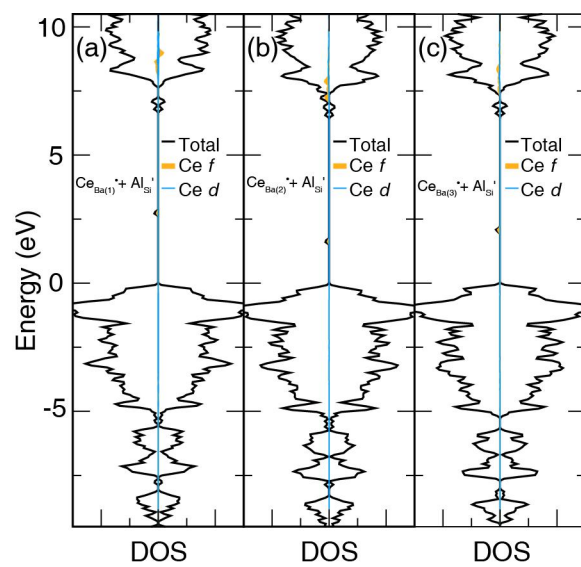


Figure S2 Total and orbital-projected DOSs for a) $\text{Ce}_{\text{Ba}(1)}^* + \text{Al}_{\text{Si}}'$, b) $\text{Ce}_{\text{Ba}(2)}^* + \text{Al}_{\text{Si}}'$, c) $\text{Ce}_{\text{Ba}(3)}^* + \text{Al}_{\text{Si}}'$ in the $\text{Ba}_5\text{Si}_8\text{O}_{21}$ obtained from the standard DFT-PBE0 method.